

# Low Voltage Standard Rectifier

$$V_{RRM} = 800\text{ V}$$

$$I_{FAV} = 20\text{ A}$$

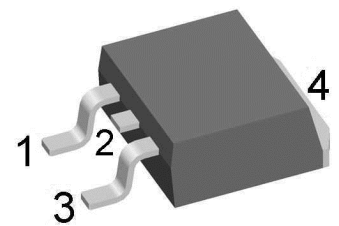
$$V_F = 1.22\text{ V}$$

Single Diode

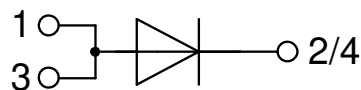
**Part number**

**DLA20IM800PC**

Marking on Product: DLA20IM800PC



Backside: cathode



## Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

## Applications:

- Diode for main rectification
- For single and three phase bridge configurations

## Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

## Disclaimer Notice

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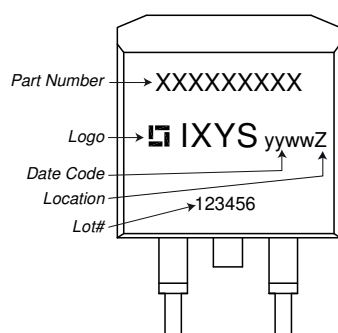


| Rectifier  |                                              |                                                   |                                             | Ratings                        |      |      |                  |
|------------|----------------------------------------------|---------------------------------------------------|---------------------------------------------|--------------------------------|------|------|------------------|
| Symbol     | Definition                                   | Conditions                                        |                                             | min.                           | typ. | max. | Unit             |
| $V_{RSM}$  | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}\text{C}$                     |                                             |                                |      | 900  | V                |
| $V_{RRM}$  | max. repetitive reverse blocking voltage     | $T_{VJ} = 25^{\circ}\text{C}$                     |                                             |                                |      | 800  | V                |
| $I_R$      | reverse current                              | $V_R = 800\text{ V}$                              | $T_{VJ} = 25^{\circ}\text{C}$               |                                |      | 5    | $\mu\text{A}$    |
|            |                                              | $V_R = 800\text{ V}$                              | $T_{VJ} = 150^{\circ}\text{C}$              |                                |      | 0.05 | mA               |
| $V_F$      | forward voltage drop                         | $I_F = 20\text{ A}$                               | $T_{VJ} = 25^{\circ}\text{C}$               |                                |      | 1.25 | V                |
|            |                                              | $I_F = 40\text{ A}$                               |                                             |                                |      | 1.49 | V                |
|            |                                              | $I_F = 20\text{ A}$                               | $T_{VJ} = 150^{\circ}\text{C}$              |                                |      | 1.22 | V                |
|            |                                              | $I_F = 40\text{ A}$                               |                                             |                                |      | 1.54 | V                |
| $I_{FAV}$  | average forward current                      | $T_C = 140^{\circ}\text{C}$<br>rectangular        | $T_{VJ} = 175^{\circ}\text{C}$<br>$d = 0.5$ |                                |      | 20   | A                |
| $V_{F0}$   | threshold voltage                            | } for power loss calculation only                 |                                             | $T_{VJ} = 175^{\circ}\text{C}$ |      | 0.88 | V                |
| $r_F$      | slope resistance                             |                                                   |                                             |                                |      | 17   | m $\Omega$       |
| $R_{thJC}$ | thermal resistance junction to case          |                                                   |                                             |                                |      | 1    | K/W              |
| $R_{thCH}$ | thermal resistance case to heatsink          |                                                   |                                             |                                | 0.25 |      | K/W              |
| $P_{tot}$  | total power dissipation                      | $T_C = 25^{\circ}\text{C}$                        |                                             |                                |      | 150  | W                |
| $I_{FSM}$  | max. forward surge current                   | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}\text{C}$               |                                |      | 200  | A                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                          |                                |      | 215  | A                |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}\text{C}$              |                                |      | 170  | A                |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                          |                                |      | 185  | A                |
| $I^2t$     | value for fusing                             | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 45^{\circ}\text{C}$               |                                |      | 200  | A <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                          |                                |      | 190  | A <sup>2</sup> s |
|            |                                              | $t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$  | $T_{VJ} = 150^{\circ}\text{C}$              |                                |      | 145  | A <sup>2</sup> s |
|            |                                              | $t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$ | $V_R = 0\text{ V}$                          |                                |      | 140  | A <sup>2</sup> s |
| $C_J$      | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$            |                                             |                                | 7    |      | pF               |

| Package TO-263 (D2Pak) |                              |                            | Ratings |      |      |      |
|------------------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol                 | Definition                   | Conditions                 | min.    | typ. | max. | Unit |
| $I_{RMS}$              | RMS current                  | per terminal <sup>1)</sup> |         |      | 35   | A    |
| $T_{VJ}$               | virtual junction temperature |                            | -55     |      | 175  | °C   |
| $T_{op}$               | operation temperature        |                            | -55     |      | 150  | °C   |
| $T_{stg}$              | storage temperature          |                            | -55     |      | 150  | °C   |
| <b>Weight</b>          |                              |                            |         | 1.5  |      | g    |
| $F_c$                  | mounting force with clip     |                            | 20      |      | 60   | N    |

<sup>1)</sup>  $I_{RMS}$  is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

## Product Marking



## Part description

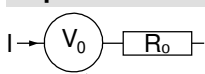
D = Diode  
 L = Low Voltage Standard Rectifier  
 A = (up to 1200V)  
 20 = Current Rating [A]  
 IM = Single Diode  
 800 = Reverse Voltage [V]  
 PC = TO-263AB (D2Pak) (2)

| Ordering    | Ordering Number  | Marking on Product | Delivery Mode | Quantity | Code No. |
|-------------|------------------|--------------------|---------------|----------|----------|
| Standard    | DLA20IM800PC-TRL | DLA20IM800PC       | Tape & Reel   | 800      | 506475   |
| Alternative | DLA20IM800PC-TUB | DLA20IM800PC       | Tube          | 50       | 506628   |

## Equivalent Circuits for Simulation

\* on die level

$T_{VJ} = 175^{\circ}\text{C}$



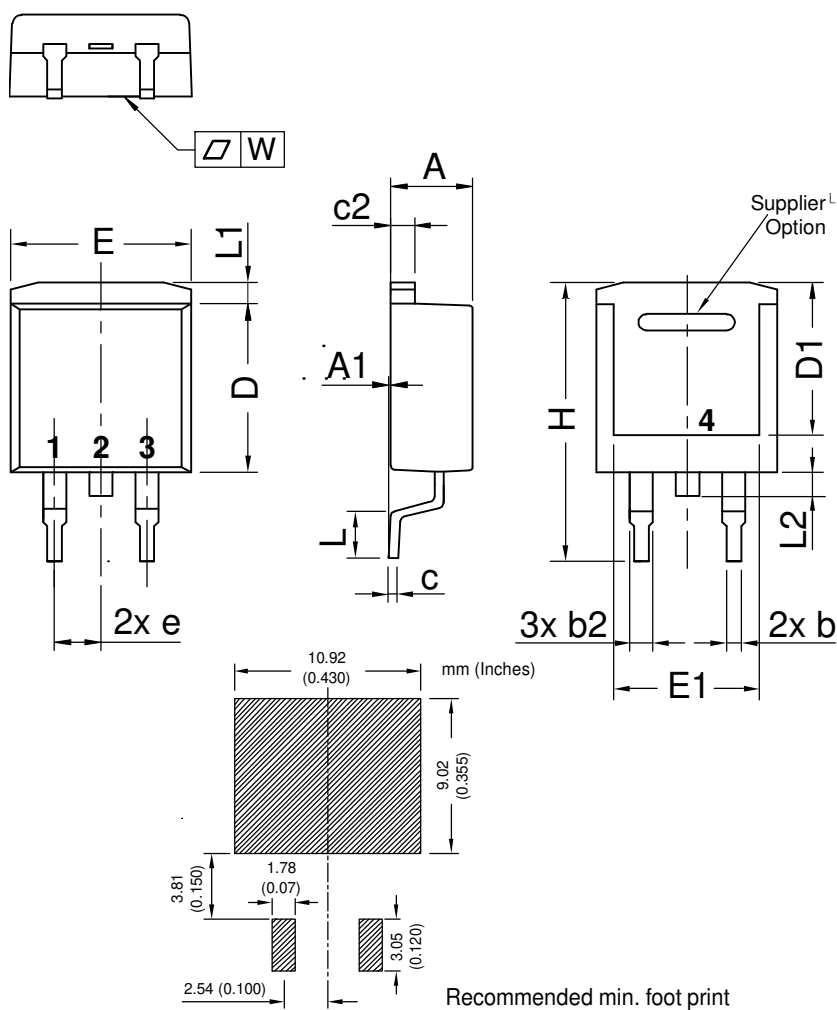
Rectifier

$V_{0\max}$  threshold voltage 0.88

$R_{0\max}$  slope resistance \* 13

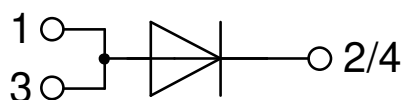
V

mΩ

**Outlines TO-263 (D2Pak)**


| Dim. | Millimeter |       | Inches      |       |
|------|------------|-------|-------------|-------|
|      | min        | max   | min         | max   |
| A    | 4.06       | 4.83  | 0.160       | 0.190 |
| A1   | typ. 0.10  |       | typ. 0.004  |       |
| A2   | 2.41       |       | 0.095       |       |
| b    | 0.51       | 0.99  | 0.020       | 0.039 |
| b2   | 1.14       | 1.40  | 0.045       | 0.055 |
| c    | 0.40       | 0.74  | 0.016       | 0.029 |
| c2   | 1.14       | 1.40  | 0.045       | 0.055 |
| D    | 8.38       | 9.40  | 0.330       | 0.370 |
| D1   | 8.00       | 8.89  | 0.315       | 0.350 |
| D2   | 2.5        |       | 0.098       |       |
| E    | 9.65       | 10.41 | 0.380       | 0.410 |
| E1   | 6.22       | 8.50  | 0.245       | 0.335 |
| e    | 2.54 BSC   |       | 0.100 BSC   |       |
| e1   | 4.28       |       | 0.169       |       |
| H    | 14.61      | 15.88 | 0.575       | 0.625 |
| L    | 1.78       | 2.79  | 0.070       | 0.110 |
| L1   | 1.02       | 1.68  | 0.040       | 0.066 |
| W    | typ. 0.02  | 0.040 | typ. 0.0008 | 0.002 |

*All dimensions conform with and/or within JEDEC standard.*



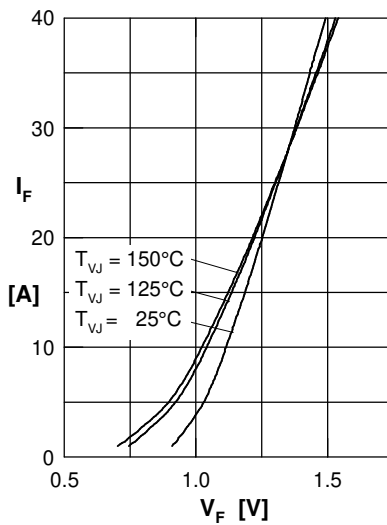
**Rectifier**


Fig. 1 Forward current versus voltage drop

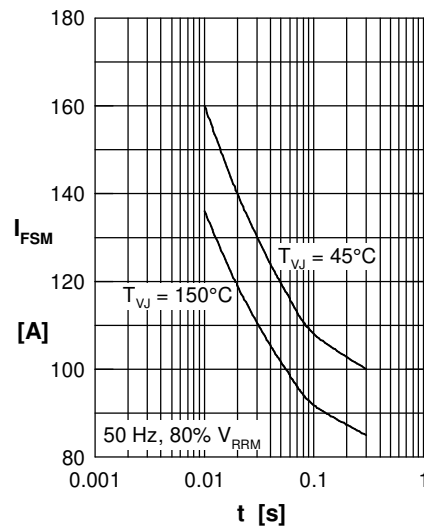


Fig. 2 Surge overload current

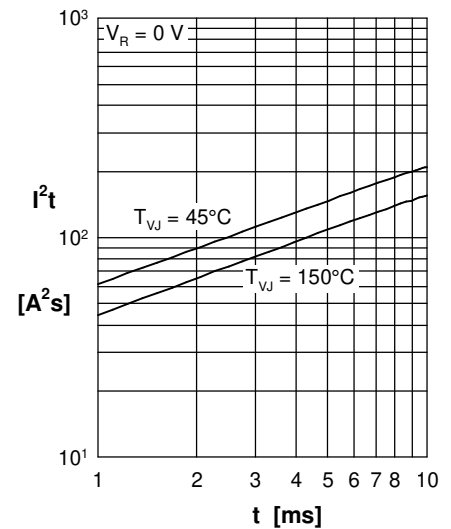
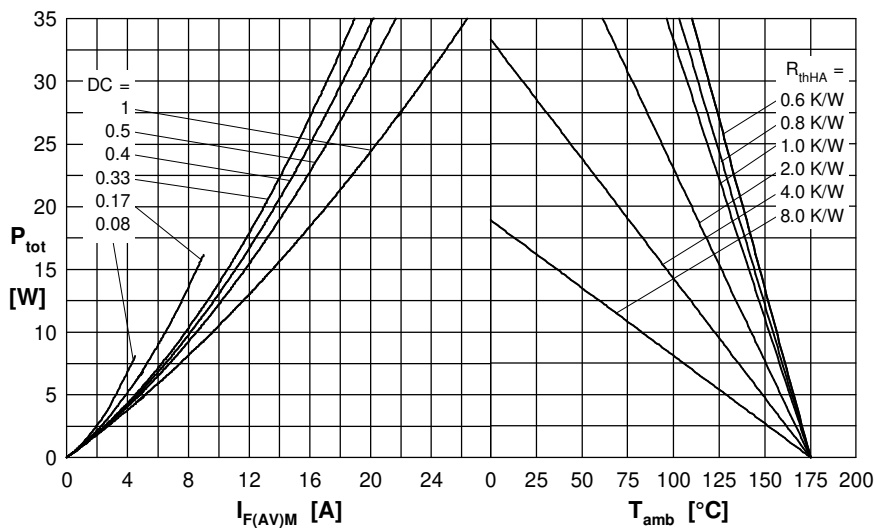

 Fig. 3  $I^2t$  versus time


Fig. 4 Power dissipation versus direct output current and ambient temperature

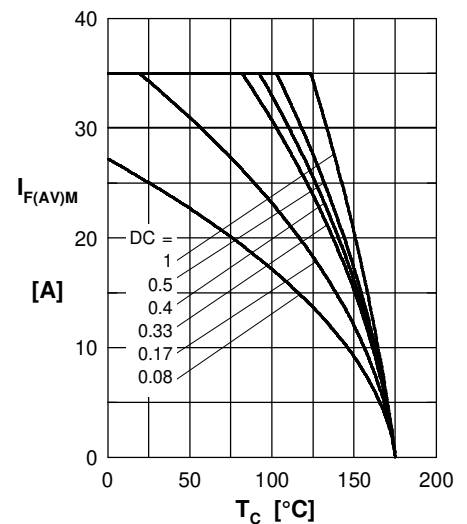


Fig. 5 Max. forward current vs. case temperature

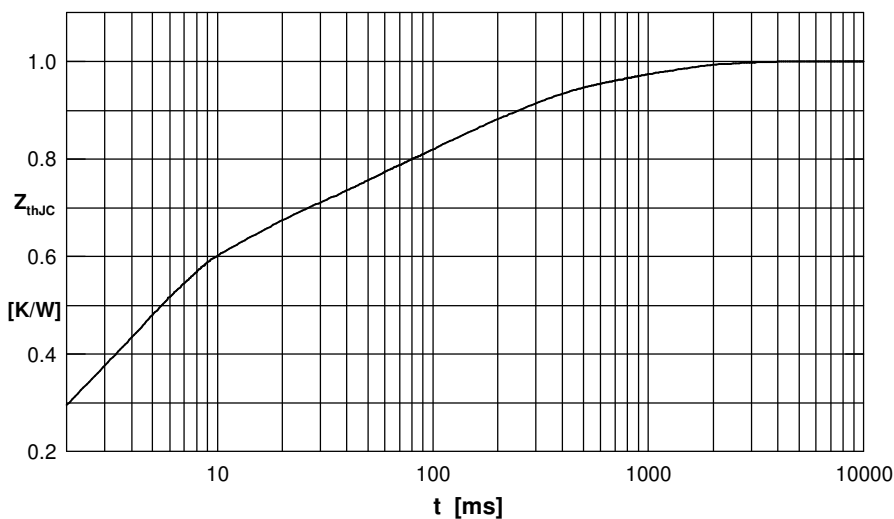


Fig. 6 Transient thermal impedance junction to case

 Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.51            | 0.0035    |
| 2 | 0.06            | 0.0003    |
| 3 | 0.14            | 0.0250    |
| 4 | 0.09            | 0.8000    |
| 5 | 0.20            | 0.1400    |